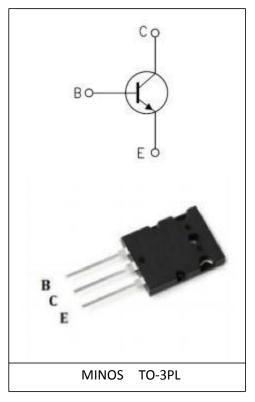


Minos High Power Products NPN TRANSISTORS

Features:

- Power Amplifier Applications
- 2 Complementary to 2SA1943
- (3) High collector voltage:VCEO=230V (min)
- 4 Recommended for 100-W high-fidelity audio frequency amplifier Output stage

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



Absolute Maximum Ratings (Tc=25 $^{\circ}$ C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V сво	230	V
Collector-emitter voltage		VCEO	230	V
Emitter-base voltage		VEBO	7	V
Collector current		Ic	17	Α
Base current		Ів	3	А
Collector power dissipation	Tc=25°C	Pc	180	W
Junction temperature	1	Tj	150	$^{\circ}$ C
Storage temperature range		Тѕтб	-55~150	$^{\circ}$ C

Package Marking And Ordering Information:

Ordering Codes	Package	Product Code	Packing
2SC5200	TO-3PL	5200	Tube



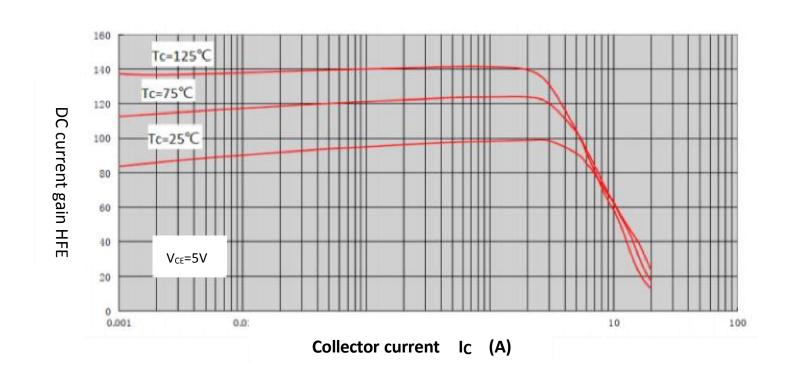
Electrical CharacteristicsTc= $(25^{\circ}C)$

Characteristics	Symbol	Т	est Condition	Min	Тур	Max	Unit
Collector cut-off current	Ісво	VcB=230V;	I _E =0			500	uA
Emitter cut-off current	ЕВО	VEB=7V;	$I_c=0$			500	uA
Dc current gain	hfe	Ic=5A;	V _{CE} =4V;	70		140	
Collector-emitter saturation voltage	Vce(sat)	Ic=4A;	I _B =0.4A			0.5	V
Transition frequency	f⊤	Vce=10V;	Ice=500mA ;f=1MHZ		58		MHZ

Symbol	Paramter	Тур	Units
R _θ јс	Junction-to-Case	0.68	°C/W

TYPICAL CHARACTERISTICS

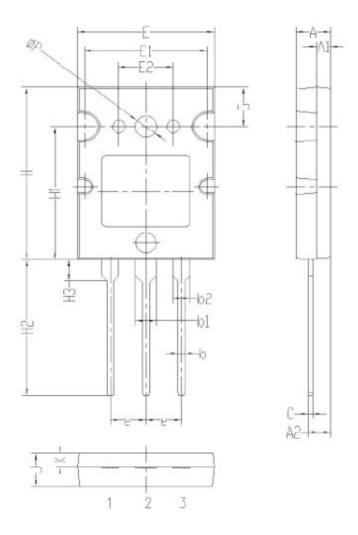
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Package Information

TO-3PL PACKAGE



		推 mm	
	MIN	NOM	MAX
Α	4.8	5	5.2
Α.	1.8	2	2.2
A2	3	3.2	3.4
b	0.8	1	1.2
b1	2.8	3	3.2
b2	2.3	2.5	2.7
С	0.4	0.6	0.8
е	5.25	5.45	5.65
E	19.8	20	20.2
E1	17.8	18	18.2
E2	7.8	8	8.2
Н	25.8	26	26.2
H1	19.8	20	20.2
H2	20	20.5	21
НЗ	3.05	3.25	3.45
G	5.8	6	6.2
ØΡ	3.1	3.3	3.5
J	4.8	5	5.2
K	1.8	2	2.2



NOTE:

- 1. Exceeding the maximum ratings of the device in performance may cause damage to the device, even the permanent failure, which may affect the dependability of the machine. Please do not exceed the absolute maximum ratings of the device when circuit designing.
- 2. When installing the heat sink, please pay attention to the torsional moment and the smoothness of the heat sink.
- 3. MOSFETs is the device which is sensitive to the static electricity, it is necessary to protect the device from being damaged by the static electricity when using it.
- 4. Shenzhen Minos reserves the right to make changes in this specification sheet and is subject to change without prior notice.

CONTACT:

深圳市迈诺斯科技有限公司(总部)

地址:深圳市福田区华富街道田面社区深南中路4026号田面城市大厦22B-22C

邮编:518025

电话: 0755-83273777